# MA2SD100G

## Silicon epitaxial planar type

For super high speed switching

#### ■ Features

- Forward current (Average)  $I_{F(AV)} = 200$  mA rectification is possible
- Low forward voltage V<sub>F</sub>
- High-density mounting is possible

#### Package

- Code

### ■ Absolute Maximum Ratings $T_a = 25$ °C

<ul> <li>Forward current (Average) I</li> <li>Low forward voltage V<sub>F</sub></li> <li>High-density mounting is I</li> </ul> Absolute Maximum R	possible		on is possible	• Code SSMini2-F4 • Pin Name 1: Anode 2: Cathode
Parameter	Symbol	Rating	Unit	■ Marking Symbol: 2L
Reverse voltage	V <sub>R</sub>	20	V	Oll 97
Repetitive peak reverse voltage	V <sub>RRM</sub>	20	V	of Society.
Forward current (Average)	$I_{F(AV)}$	200	mA	al calle still
Peak forward current	$I_{FM}$	300	ShA N	10.00
Non-repetitive peak forward surge current *	$I_{FSM}$	1	, ACV	daye edles
Junction temperature	$T_{j}$	125	CO20 O	, , , , , , , , , , , , , , , , , , ,
Storage temperature	T <sub>stg</sub>	-55 to +125	60	
Note) *: The peak-to-peak value in	700	0 Hz sine wave	(non-repetitive)	ntact
Parameter	Syml	por	Condition	ns Min Typ Max

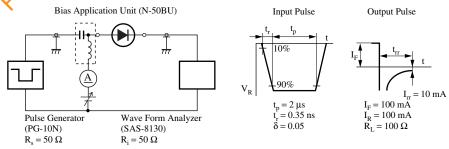
Note) \*: The peak-to-peak value in one cycle of 50 Hz sine wave (non-repetitive)

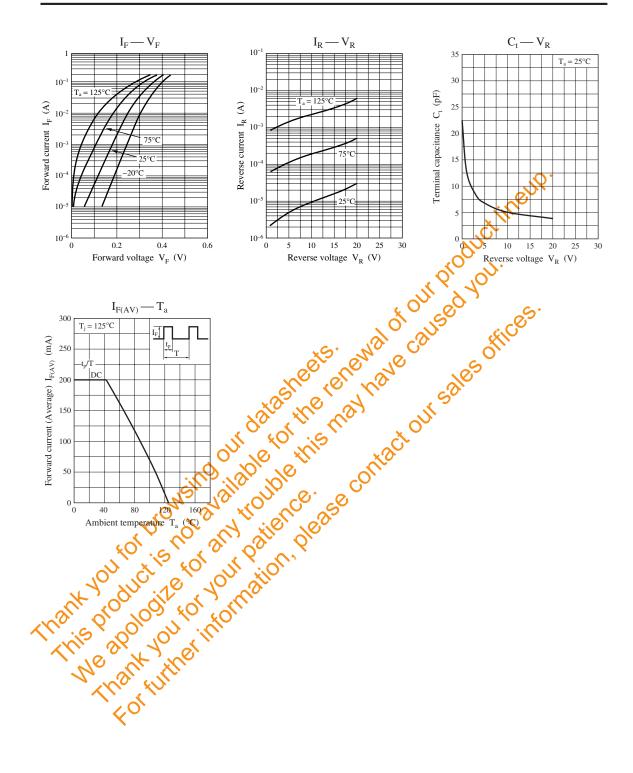
# ■ Electrical Characteristics

Parameter Symbol Conditions	Min	Тур	Max	Unit
Forward voltage $V_{F1} = 5 \text{ m/s}$			0.27	V
$V_{\rm F2}$ $I_{\rm F}$ = 100 mA			0.40	
V <sub>F3</sub> V <sub>F3</sub> ≥ 200 mA			0.47	
Reverse current $V_R = 10 \text{ V}$			20	μΑ
Terminal capacitance $V_R = 0 \text{ V}, f = 1 \text{ MHz}$		25		pF
Reverse recovery time $I_F = I_R = 100 \text{ mA}$		3		ns
$I_{rr} = 10 \text{ mA}, R_L = 100 \Omega$				

Note 1 Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

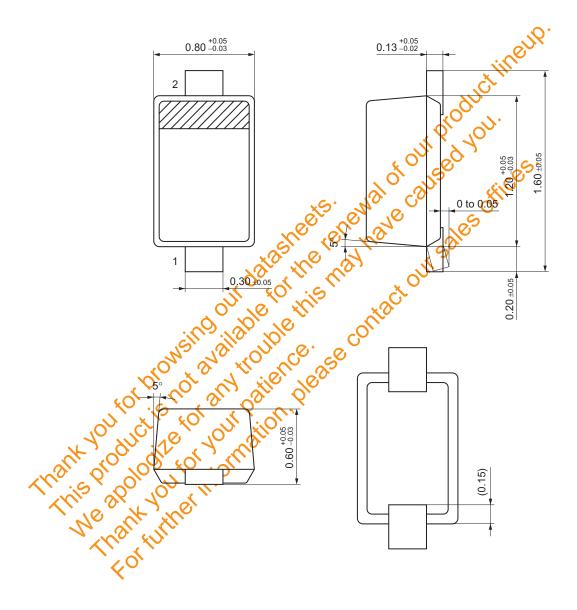
- 2. The products sensificate electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
- 3. Absolute frequency of input and output is 250 MHz.
- 4. \*: t<sub>rr</sub> measurement circuit





2 SKH00176AED

SSMini2-F4 Unit: mm



SKH00176AED 3

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